# NSN 5961-01-225-8661

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# Inclosure Material:

Metal

**Overall Length:** 

1.573 inches

# **Overall Height:**

0.450 inches

**Overall Width:** 

1.050 inches

# **Mounting Facility Quantity:**

2

#### Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### T0-3

Electrode Internally-electrically Connected To Case:

Collector

#### Mounting Method:

Unthreaded hole

## Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

850.0 collector-to-emitter substaining voltage, with specified circuit between base and emitter and 400.0 collector to emitter

voltage/static/base open and 7.0 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

15.00 amperes source cutoff current and 10.00 amperes source cutoff current

## Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector preset

#### Transfer Ratio:

6.0 static forward current transfer ratio, common-emitter

# Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

# **Special Features:**

Junction pattern arrangement: npn

# Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

No

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